L Number	Hits	Search Text	DB	Time stamp
1	1021	438/424.ccls.	USPAT	2004/10/20
				17:56
2	212	438/425.ccls.	USPAT	2004/10/20
				17:56
3	180	438/426.ccls.	USPAT	2004/10/20
				17:56
4	347	438/427.ccls.	USPAT	2004/10/20
				17:56
5	275	438/430.ccis.	USPAT	2004/10/20
				17:57
6	139	438/431.ccls.	USPAT	2004/10/20
				17:57
7	279	438/439.ccls.	USPAT	2004/10/20
				17:57
8	132	438/444.ccls.	USPAT	2004/10/20
				17:57
9	41	438/446.ccls.	USPAT	2004/10/20
				17:57
10	138	438/448.ccls.	USPAT	2004/10/20
				17:57
11	723	438/700.ccls.	USPAT	2004/10/20
				17:57
12	73	438/295.ccls.	USPAT	2004/10/20
				17:58
13	496	438/296.ccls.	USPAT	2004/10/20
14				17:58
	424	438/297.ccls.	USPAT	2004/10/20
4=				17:58
15	242	438/294.ccls.	USPAT	2004/10/20
				17:58
16	1	takenaka-masahiro\$.in.	USPAT	2004/10/20
		4.1		18:00
17	3	takenaka-masahiro\$.in.	US-PGPUB	2004/10/20
				17:59
18	25	takenaka-masahiro\$.in.	EPO; JPO;	2004/10/20
			DERWENT;	17:59
40	40040	// ***	IBM_TDB	
19	12813	((silicon same germanium) "sige") and	USPAT	2004/10/20
	0004	(trench groov\$6 open\$6 recess\$6)		18:04
20	2061	(((silicon same germanium) "sige") and	USPAT	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and		18:03
21	361	(strain\$6 relax\$6)	HEDAT	2004/40/20
	307	((((silicon same germanium) "sige") and	USPAT	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and		18:04
		(strain\$6 relax\$6)) and (strain\$6 and		
22	754	relax\$6)	HODAT	0004/40/00
22	194	((((silicon same germanium) "sige") and (trench groov\$6 open\$6 recess\$6)) and	USPAT	2004/10/20
		(trench groovab openab recessab)) and (strain\$6 relax\$6)) and oxidiz\$9		18:04

23	445	(((((silicon same germanium) "sige") and	USPAT	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and		18:04
		(strain\$6 relax\$6)) and oxidiz\$9) and		
		(oxidiz\$9 same (silicon polysilicon))		
24	5850	((silicon same germanium) "sige") and	US-PGPUB	2004/10/20
		(trench groov\$6 open\$6 recess\$6)		18:05
25	468	(((silicon same germanium) "sige") and	US-PGPUB	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and		18:05
		(strain\$6 and relax\$6)		_
26	305	((((silicon same germanium) "sige") and	US-PGPUB	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and		18:05
		(strain\$6 and relax\$6)) and oxidiz\$9		
27	700	((silicon same germanium) "sige") and	EPO; JPO;	2004/10/20
		(trench groov\$6 open\$6 recess\$6)	DERWENT;	18:06
			IBM_TDB	
28	4	(((silicon same germanium) "sige") and	EPO; JPO;	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and	DERWENT;	18:05
		(strain\$6 and relax\$6)	IBM_TDB	
29	39	(((silicon same germanium) "sige") and	EPO; JPO;	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and	DERWENT;	18:05
		oxidiz\$9	IBM_TDB	
30	443	(((silicon same germanium) "sige") and	EPO; JPO;	2004/10/20
		(trench groov\$6 open\$6 recess\$6)) and	DERWENT;	18:06
		(((silicon same germanium) "sige") same	IBM_TDB	
		(trench groov\$6 open\$6 recess\$6))		